

BGS22WL10

DPDT (Dual-Pole / Double-Throw) Differential RF Switch

Data Sheet

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Revision History

Previous Version: v1.6, May 27, 2014

Page	Subjects (major changes since last revision)
9	Updated Maximum Ratings (Table 3)

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BGS22WL10 DPDT (Dual-Pole / Double-Throw) Differential RF Switch

1 Features

- DPDT (Dual-Pole / Double-Throw) differential RF switch
- Frequency range: 0.1 - 3 GHz
- High signal power up to 30 dBm
- Supply voltage 2.3 - 3.6 V
- Small package size of 1.55 x 1.15 mm²
- No decoupling capacitors required if no DC applied
- RoHS compliant package



2 Product Description

The BGS22WL10 is a DPDT (Dual-Pole / Double Throw) RF switch which combines two differential signals into one differential output or splits one differential signal into two separate differential lines. The parallel paths of the switch are controlled simultaneously through the same signals. The switch is designed to operate in battery powered applications with a supply voltage range of 2.4 - 3.6 V. The highly symmetric design ensures best phase- and amplitude accuracy.

A typical application is to combine two Rx paths in a mobile cellular device after the Rx filters or duplexers into one input to the transceiver IC. The IC can also be used for a wide variety of applications switching balanced signals in a frequency range of 0.1 - 3 GHz. The RF switch is packaged in a standard RoHS compliant TSLP-10-1 package with a small outline of only 1.55 x 1.15 mm².

No decoupling capacitors are required in typical applications as long as no DC is applied to any RF port.

Table 1: Ordering Information

Type	Package	Marking
BGS22WL10	TSLP-10-1	22W

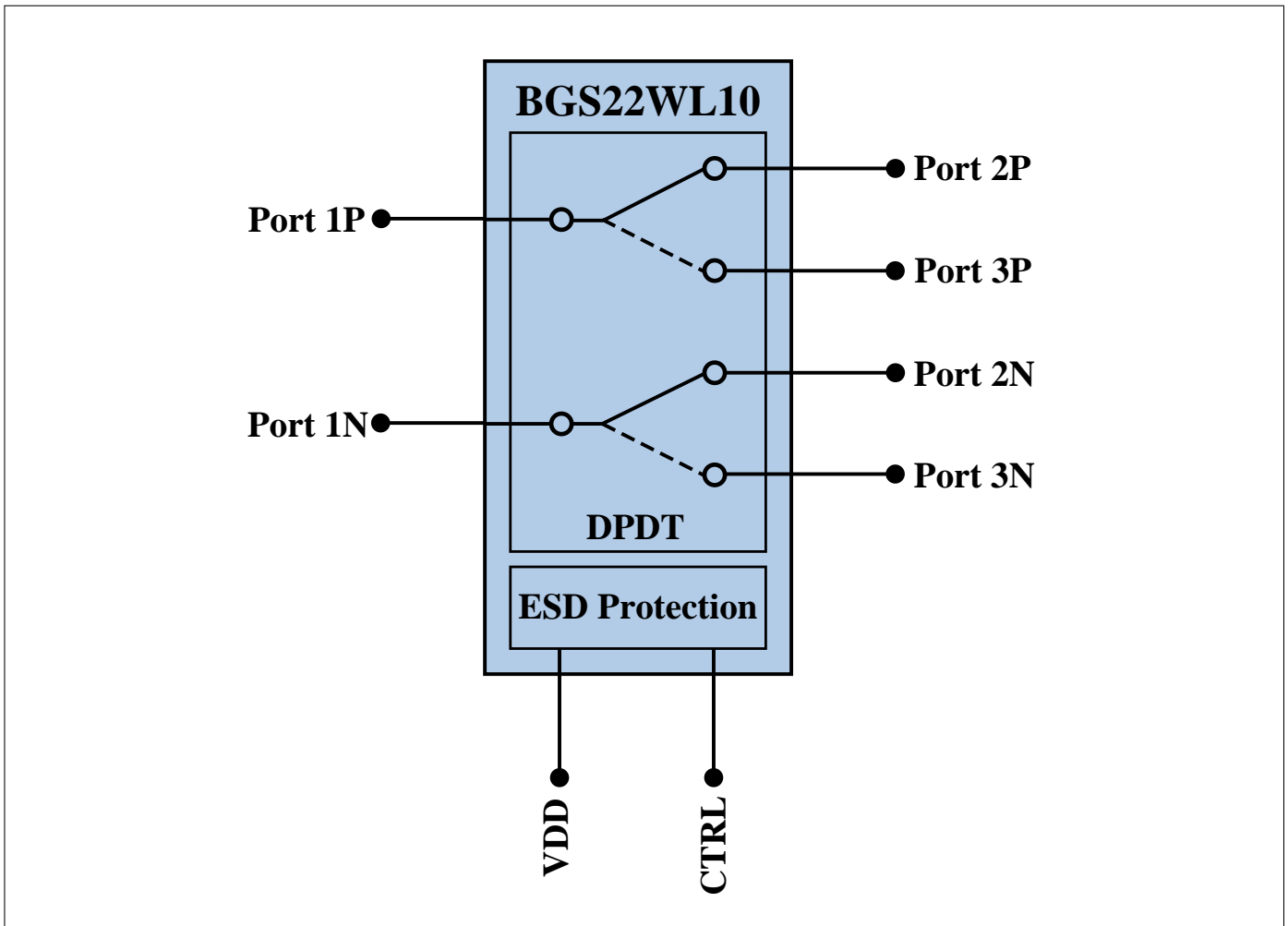


Figure 1: BGS22WL10 block diagram

Table 2: Truth Table

Pin No.	CRTL
Port 1 to Port 2	0
Port 1 to Port 3	1

3 Maximum Ratings

Table 3: Maximum Ratings at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply voltage	V_{DD}	-0.5	–	5.5	V	–
Control voltage	V_{Ctrl}	-0.3	–	3.6	V	–
Storage temperature range	T_{STG}	-55	–	150	°C	–
RF input power	P_{In}	–	–	+32	dBm	–
ESD capability Human Body Model	V_{ESD_HBM}	1000	–	–	V	–
Junction temperature	T_j	–	–	125	°C	–
Thermal resistance junction - soldering point	R_{thJS}	–	–	43	K/W	–

Attention:

Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

4 Operation Ranges

Table 4: Operation Ranges

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply Voltage	V_{DD}	2.3	–	3.6	V	–
Control Voltage Low	V_{Ctrl_L}	-0.3	–	0.4	V	–
Control Voltage High	V_{Ctrl_H}	1.2	–	V_{DD}	V	–
RF frequency	f_{RF}	0.1	–	–	GHz	–
Ambient Temperature	T_A	-40	25	85	°C	–

Table 5: RF Input Power

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
RF Input Power (50Ω)	P_{In}	–	–	30	dBm	–

5 RF Characteristics

Table 6: RF Characteristics:

 Terminating port impedance: $Z_0 = 50 \Omega$

Measurement conditions unless otherwise specified:

 $T_A = 25 \text{ }^\circ\text{C}$, $P_{IN} = 0 \text{ dBm}$, Supply Voltage $V_{DD} = 2.3 - 3.6 \text{ V}$

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Insertion Loss - Typical Conditions: $T_A = 25 \text{ }^\circ\text{C}$, $V_{DD} = 3 \text{ V}$						
	IL	0.30	0.34	0.39	dB	824 - 915 MHz
		0.37	0.40	0.46	dB	1710 - 1910 MHz
		0.43	0.48	0.59	dB	2170 - 2690 MHz
Insertion Loss - Min/Max Conditions: $T_A = -40 \dots +85 \text{ }^\circ\text{C}$, $V_{DD} = 2.3 \dots 3.6 \text{ V}$						
	IL	0.23	0.34	0.54	dB	824 - 915 MHz
		0.27	0.40	0.58	dB	1710 - 1910 MHz
		0.31	0.48	0.75	dB	2170 - 2690 MHz
Return Loss - Min/Max Conditions: $T_A = -40 \dots +85 \text{ }^\circ\text{C}$, $V_{DD} = 2.3 \dots 3.6 \text{ V}$						
	RL	25	27	35	dB	824 - 915 MHz
		22	26	30	dB	1710 - 1910 MHz
		16	22	25	dB	2170 - 2690 MHz
Isolation¹						
	ISO	32	38	44	dB	824 - 915 MHz
		25	30	37	dB	1710 - 1910 MHz
		22	28	33	dB	2170 - 2690 MHz
P0.1 dB Compression Point						
	$P_{0.1dB}$	33	34	35	dBm	1000 MHz
Harmonic Generation up to 12.75 GHz						
Any path	P_{Harm}	80	85	95	dBc	27 dBm, 50Ω, 25 °C, 25 % duty cycle
Intermodulation Distortion in Rx Band						
IMD2_Low ²	P_{IMD2_L}	-125	-115	-105	dBm	Tx = 15 dBm, Interferer = -15 dBm
IMD3	P_{IMD3}	-125	-115	-110	dBm	Tx = 10 dBm, Interferer = -15 dBm
IMD2_High	P_{IMD2_H}	-125	-115	-110	dBm	Tx = 10 dBm, Interferer = -15 dBm
Switching Time and Current Consumption						
RF Rise Time	$t_{10\%-90\%}$	–	250	–	ns	10% - 90% of RF Signal ($V_{DD} = 3 \text{ V}$)
Ctrl to RF Time	$t_{Ctrl-RF}$	–	600	–	ns	50% of Ctrl Signal to 90% of RF Signal ($V_{DD} = 3 \text{ V}$)
Supply Current	I_{DD}	70	120	190	μA	Current at $T_A = 25 \text{ }^\circ\text{C}$
Phase Error						
Between any two paths	Ph_{Err}	0.3	0.5	0.7	Deg.	27 dBm, 50Ω, 25 °C, 25 % duty cycle

Note: All electrical characteristics are measured with all RF ports terminated in 50 Ω.

¹ Isolation values are not dependent on supply voltage and temperature as long as operated in the specified operation range.

² With external shunt inductor.

6 Package Outline and Pin Configuration

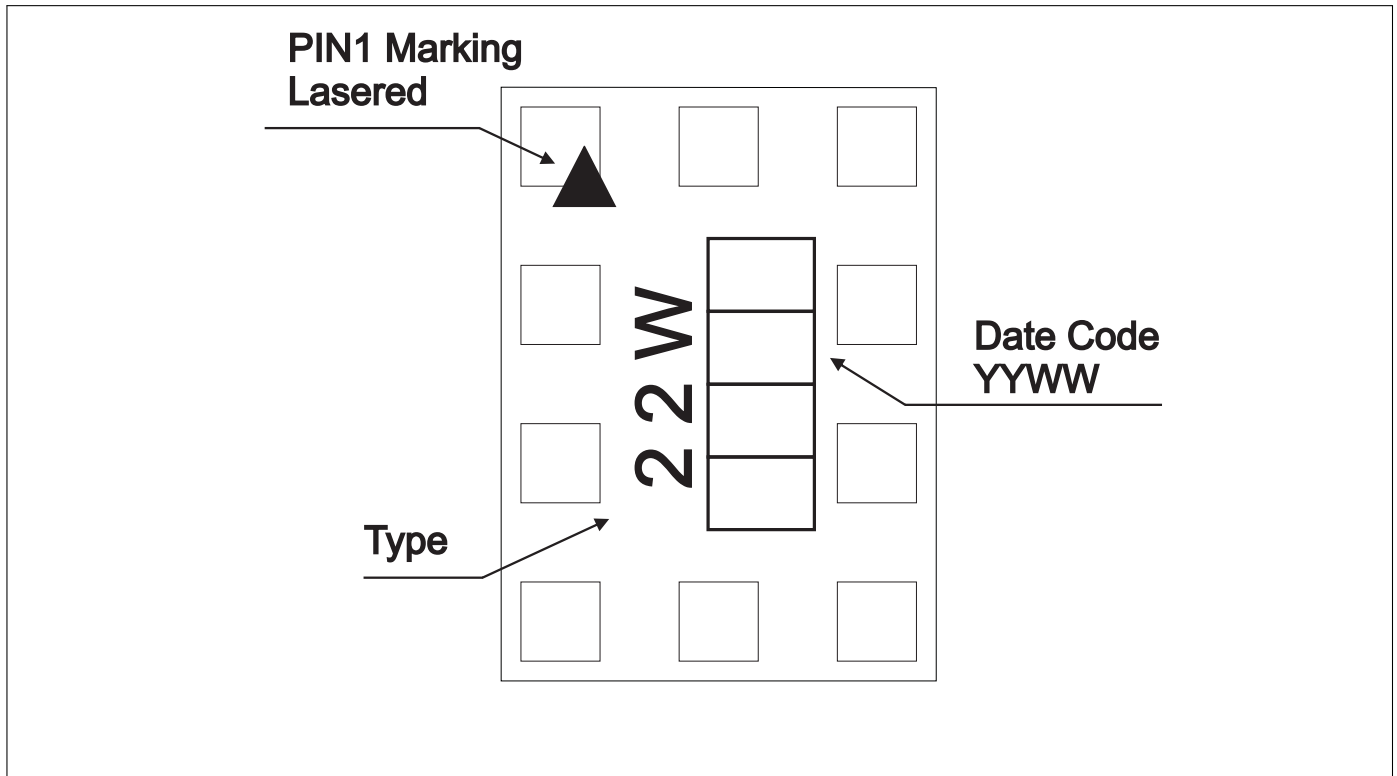


Figure 2: Marking Layout (top view)

Table 7: Pin Configuration

Pin No.	Name	Pin Type	Buffer Type	Function
1	Port 3P			Differential Output P of Port 3
2	GND			Ground Pin
3	GND			Ground Pin
4	Port 2N			Differential Output N of Port 2
5	Port 2P			Differential Output P of Port 2
6	CTRL			Control Voltage
7	Port 1P			Differential Input P of Port 1
8	Port 1N			Differential Input N of Port 1
9	VDD			Supply Voltage
10	Port 3N			Differential Output N of Port 3

Table 8: Mechanical Data

Parameter	Symbol	Value	Unit
Package X-Dimension	X	1.55 ± 0.05	mm
Package Y-Dimension	Y	1.15 ± 0.05	mm
Package Area	A	1.783	mm ²
Package Height	H	0.39 +0.01/-0.03	mm

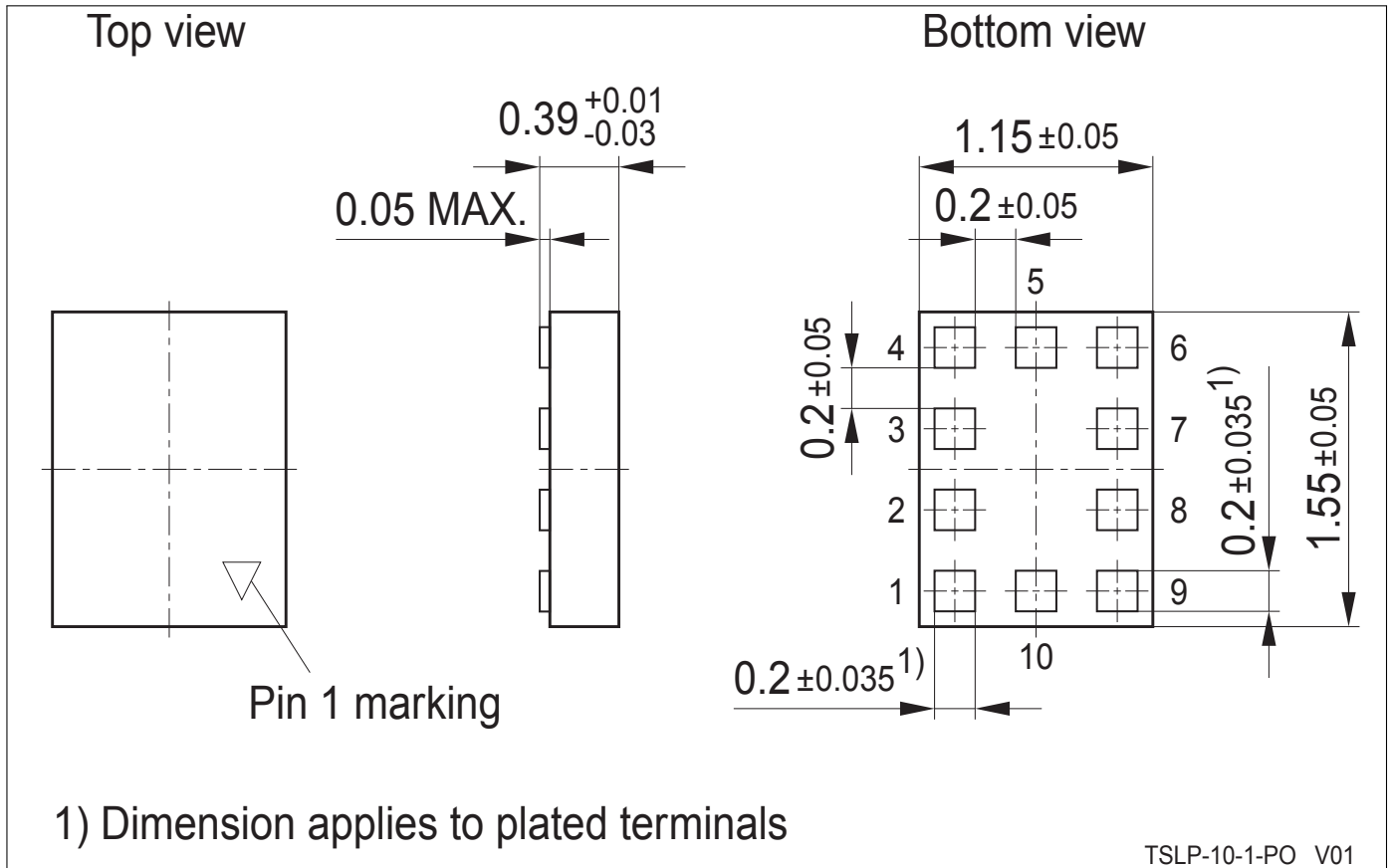


Figure 3: TSLP-10-1 Package Outline (top, side and bottom view)

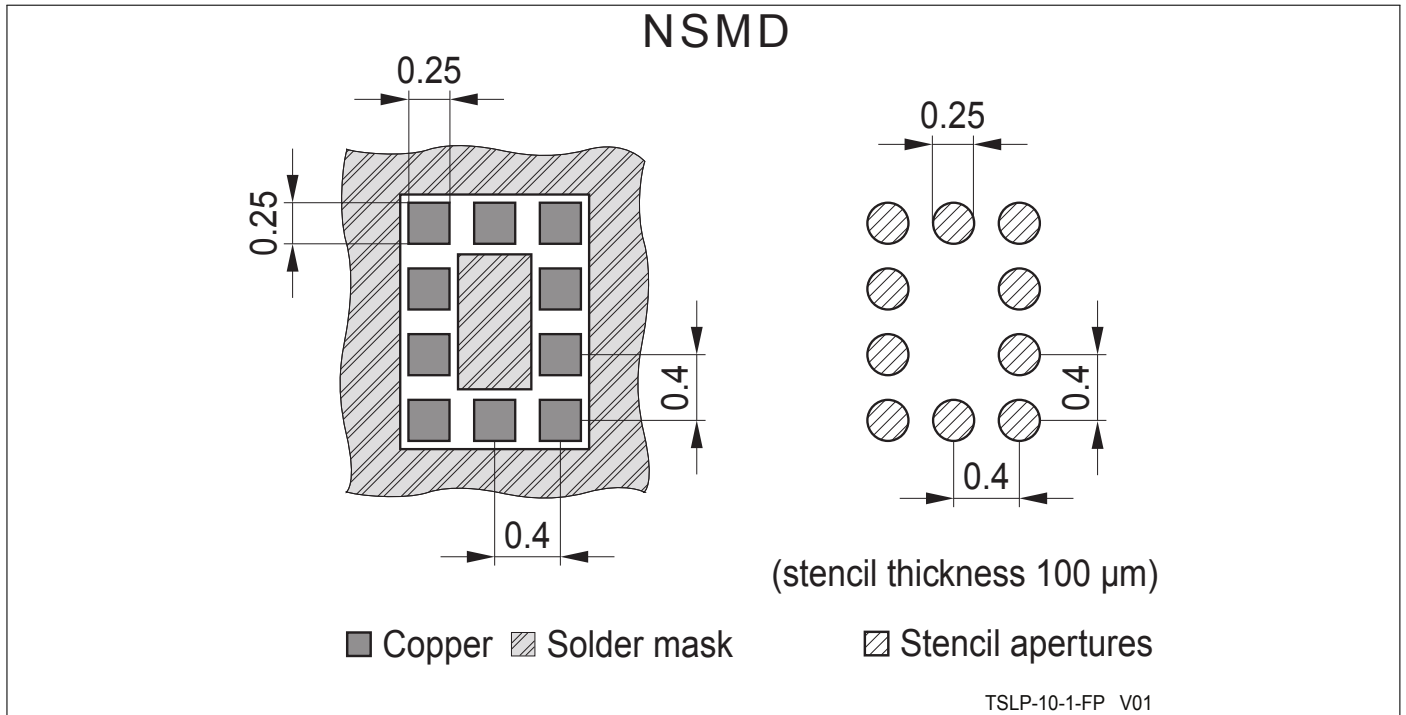


Figure 4: Footprint TSLP-10-1

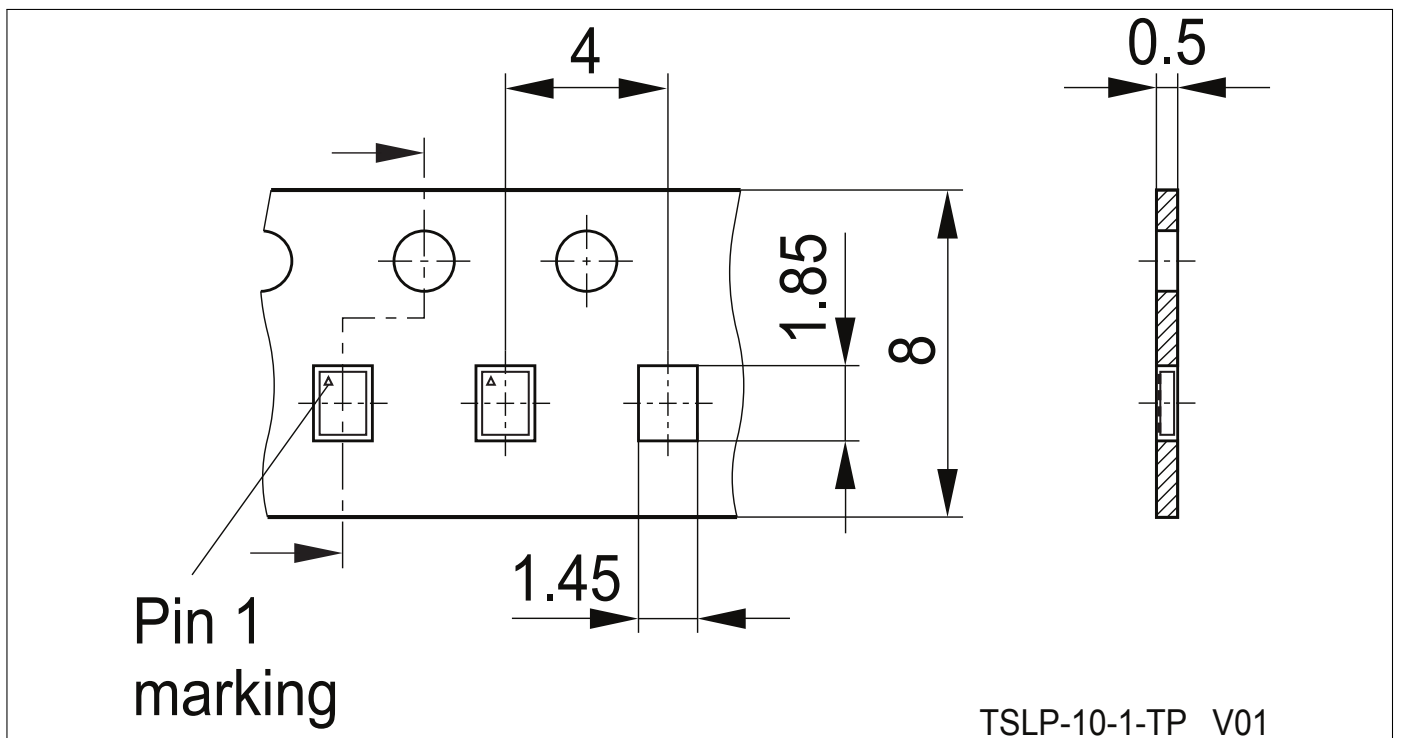


Figure 5: Tape and Reel Dimensions for TSLP-10-1

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